

5410/DM5410/DM7410 Triple 3-Input NAND Gates

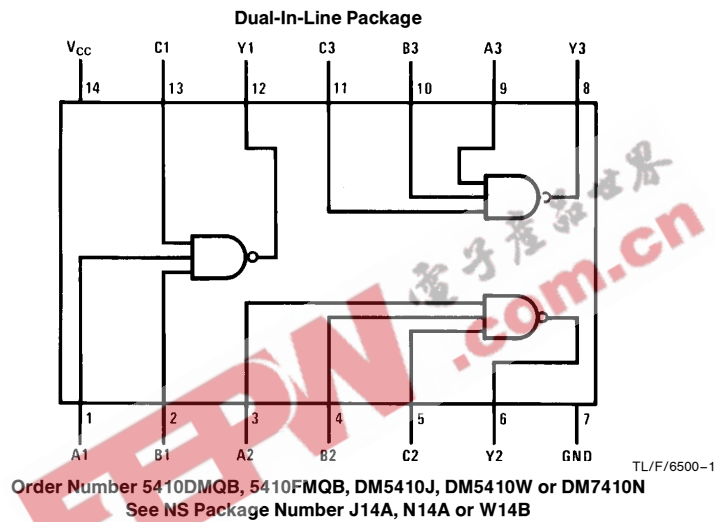
General Description

This device contains three independent gates each of which performs the logic NAND function.

Features

- Alternate Military/Aerospace device (5410) is available. Contact a National Semiconductor Sales Office/Distributor for specifications.

Connection Diagram



Function Table

$$Y = \overline{ABC}$$

Inputs			Output
A	B	C	Y
X	X	L	H
X	L	X	H
L	X	X	H
H	H	H	L

H = High Logic Level

L = Low Logic Level

X = Either Low or High Logic Level

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	7V
Input Voltage	5.5V
Operating Free Air Temperature Range	
DM54 and 54	-55°C to +125°C
DM74	0°C to +70°C
Storage Temperature Range	-65°C to +150°C

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameter	DM5410			DM7410			Units
		Min	Nom	Max	Min	Nom	Max	
V _{CC}	Supply Voltage	4.5	5	5.5	4.75	5	5.25	V
V _{IH}	High Level Input Voltage	2			2			V
V _{IL}	Low Level Input Voltage			0.8			0.8	V
I _{OH}	High Level Output Current			-0.4			-0.4	mA
I _{OL}	Low Level Output Current			16			16	mA
T _A	Free Air Operating Temperature	-55		125	0		70	°C

Electrical Characteristics over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ (Note 1)	Max	Units	
V _I	Input Clamp Voltage	V _{CC} = Min, I _I = -12 mA			-1.5	V	
V _{OH}	High Level Output Voltage	V _{CC} = Min, I _{OH} = Max V _{IL} = Max	2.4	3.4		V	
V _{OL}	Low Level Output Voltage	V _{CC} = Min, I _{OL} = Max V _{IH} = Min		0.2	0.4	V	
I _I	Input Current @ Max Input Voltage	V _{CC} = Max, V _I = 5.5V			1	mA	
I _{IH}	High Level Input Current	V _{CC} = Max, V _I = 2.4V			40	μA	
I _{IL}	Low Level Input Current	V _{CC} = Max, V _I = 0.4V			-1.6	mA	
I _{OS}	Short Circuit Output Current	V _{CC} = Max (Note 2)	DM54	-20		-55	mA
			DM74	-18		-55	
I _{CCH}	Supply Current with Outputs High	V _{CC} = Max		3	6	mA	
I _{CCL}	Supply Current with Outputs Low	V _{CC} = Max		9	16.5	mA	

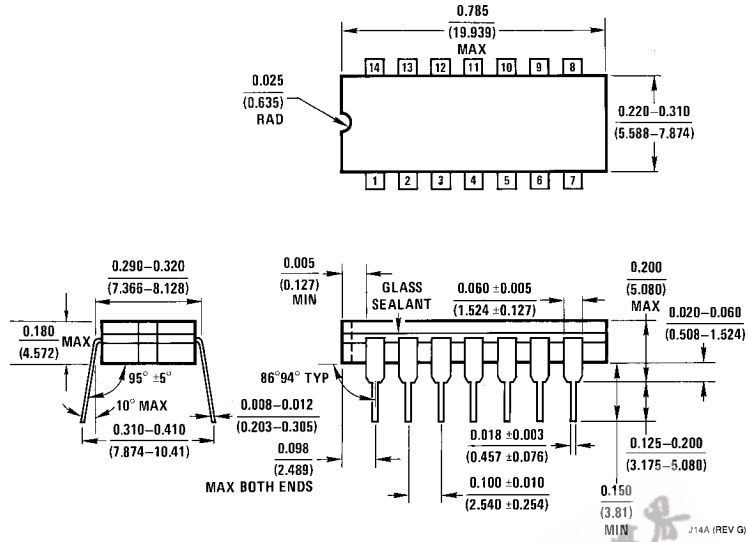
Switching Characteristics at V_{CC} = 5V and T_A = 25°C (See Section 1 for Test Waveforms and Output Load)

Symbol	Parameter	Conditions	Min	Max	Units
t _{PLH}	Propagation Delay Time Low to High Level Output	C _L = 15 pF R _L = 400Ω		22	ns
t _{PHL}	Propagation Delay Time High to Low Level Output			15	ns

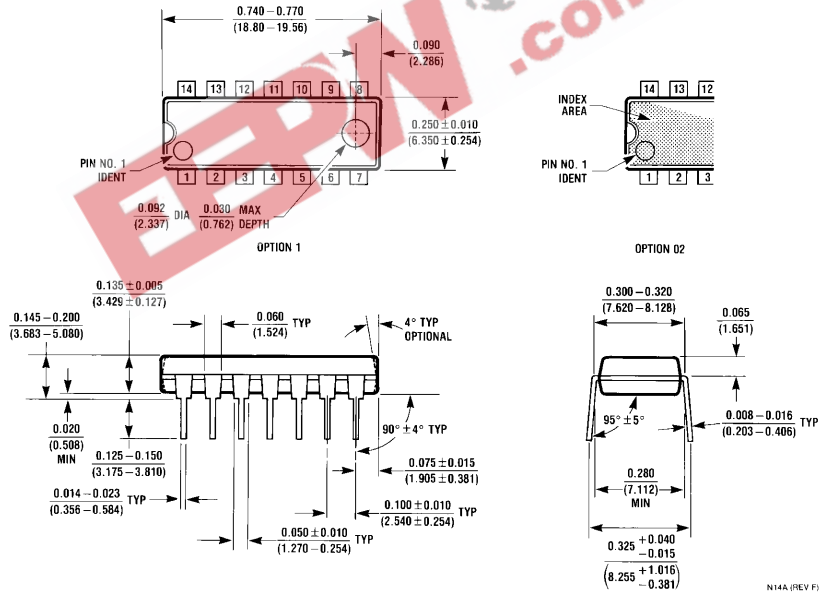
Note 1: All typicals are at V_{CC} = 5V, T_A = 25°C.

Note 2: Not more than one output should be shorted at a time.

Physical Dimensions inches (millimeters)

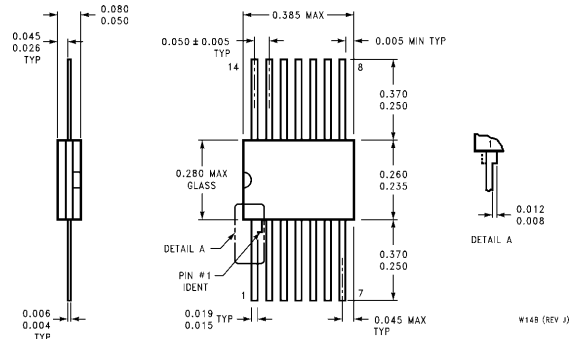


14-Lead Ceramic Dual-In-Line Package (J)
Order Number 5410DMQB or DM5410J
NS Package Number J14A



14-Lead Molded Dual-In-Line Package (N)
Order Number DM7410N
NS Package Number N14A

Physical Dimensions inches (millimeters) (Continued)



14-Lead Ceramic Flat Package (W)
Order Number 5410FMQB or DM5410W
NS Package Number W14B



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National Semiconductor Corporation
 1111 West Bardin Road
 Arlington, TX 76017
 Tel: 1(800) 272-9959
 Fax: 1(800) 737-7018

National Semiconductor Europe
 Fax: (+49) 0-180-530 85 86
 Email: cnjwge@levm2.nsc.com
 Deutsch Tel: (+49) 0-180-530 85 85
 English Tel: (+49) 0-180-532 78 32
 Français Tel: (+49) 0-180-532 93 58
 Italiano Tel: (+49) 0-180-534 16 80

National Semiconductor Hong Kong Ltd.
 13th Floor, Straight Block,
 Ocean Centre, 5 Canton Rd.
 Tsimshatsui, Kowloon
 Hong Kong
 Tel: (852) 2737-1600
 Fax: (852) 2736-9960

National Semiconductor Japan Ltd.
 Tel: 81-043-299-2309
 Fax: 81-043-299-2408

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